

# DATA SHEET

## GENERAL PURPOSE CHIP RESISTORS

RC2010 (Pb Free)  
5%, 1%



Product specification – Sep 24, 2004 V.2



**SCOPE**

This specification describes RC2010 series chip resistors with lead-free terminations made by thick film process.

**ORDERING INFORMATION**

Part number is identified by the series, size, tolerance, packing type, temperature coefficient, taping reel and resistance value.

**YAGEO ORDERING CODE**

**CTC CODE**

**RC2010**   **X** **X** **X** **XX** **XXXX** **L**  
 (1) (2) (3) (4)      (5)      (6)

**(1) TOLERANCE**

F = ±1%  
 J = ±5%

**(2) PACKAGING TYPE**

K = Embossed/ taping reel

**(3) TEMPERATURE COEFFICIENT OF RESISTANCE**

– = Base on spec

**(4) TAPING REEL**

07 = 7 inch dia. Reel

**(5) RESISTANCE VALUE**

5R6, 56R, 560R, 56K, 22M.

**(6) RESISTOR TERMINATIONS**

L = Lead free terminations (pure Tin)

**ORDERING EXAMPLE**

The ordering code of a RC2010 chip resistor, value 56 Ω with ±1% tolerance, supplied in 7-inch tape reel is: RC2010FK-0756RL.

**NOTE**

1. The “L” at the end of the code is only for ordering. On the reel label, the standard CTC will be mentioned an additional stamp “LFP”= lead free production.
2. Products with lead in terminations fulfil the same requirements as mentioned in this datasheet.
3. Products with lead in terminations will be phased out in the coming months (before July 1st, 2006)

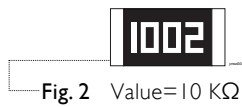
**MARKING**

RC2010



E-24 series: 3 digits

First two digits for significant figure and 3rd digit for number of zeros



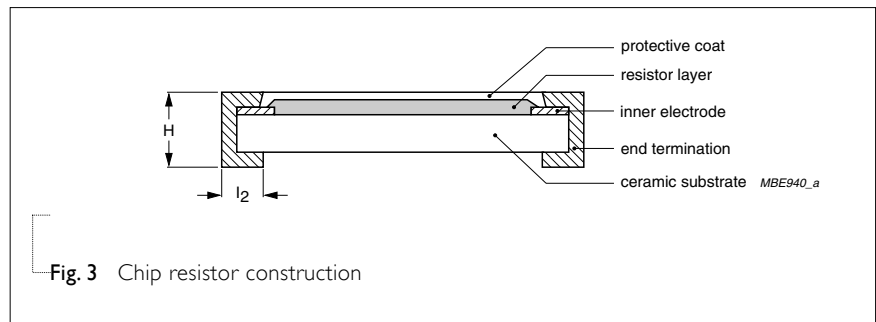
Both E-24 and E-96 series: 4 digits

First three digits for significant figure and 4th digit for number of zeros

For marking codes, please see EIA-marking code rules in data sheet “Chip resistors instruction”.

**CONSTRUCTION**

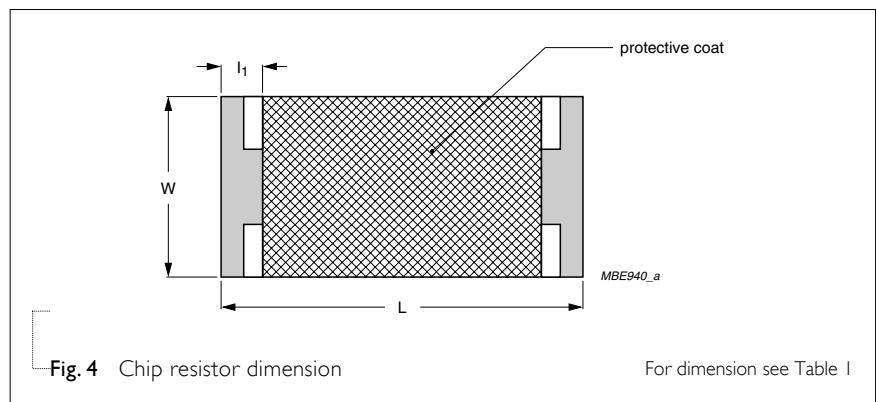
The resistors are constructed out of a high-grade ceramic body. Internal metal electrodes are added at each end and connected by a resistive paste. The composition of the paste is adjusted to give the approximate required resistance and laser cutting of this resistive layer that achieves tolerance trims the value. The resistive layer is covered with a protective coat and printed with the resistance value. Finally, the two external terminations (pure Tin) are added. See fig. 3.



**DIMENSIONS**

Table I

TYPE	RC2010
L (mm)	5.00 ±0.10
W (mm)	2.50 ±0.15
H (mm)	0.55 ±0.10
l <sub>1</sub> (mm)	0.45 ±0.15
l <sub>2</sub> (mm)	0.50 ±0.20



**ELECTRICAL CHARACTERISTICS**

Table 2

CHARACTERISTICS	RC2010 3/4 W
Operating Temperature Range	-55 °C to +155 °C
Maximum Working Voltage	200 V
Maximum Overload Voltage	500 V
Dielectric Withstanding Voltage	500 V
Resistance Range	5% (E24) 1 Ω to 22 MΩ
	1% (E96) 1 Ω to 10 MΩ
	Zero Ohm Jumper < 0.05 Ω
Temperature Coefficient	10 Ω < R ≤ 10 MΩ ±100 ppm/°C
	R ≤ 10 Ω; R > 10 MΩ ±200 ppm/°C
Jumper Criteria	Rated Current 2.0 A
	Maximum Current 10.0 A

**FOOTPRINT AND SOLDERING PROFILES**

For recommended footprint and soldering profiles, please see the special data sheet “Chip resistors mounting”.

**ENVIRONMENTAL DATA**

For material declaration information (IMDS-data) of the products, please see the separated info “Environmental data”.

**PACKING STYLE AND PACKAGING QUANTITY**

Table 3 Packing style and packaging quantity

PRODUCT TYPE	PACKING STYLE	REEL DIMENSION	QUANTITY PER REEL
RC2010	Embossed taping reel (K)	7" (178 mm)	4,000 units

**NOTE**

1. For embossed tape and reel specification/dimensions, please see the special data sheet “Packing” document.

**FUNCTIONAL DESCRIPTION**

**POWER RATING**

RC2010 rated power at 70°C is 3/4 W

**RATED VOLTAGE**

The DC or AC (rms) continuous working voltage corresponding to the rated power is determined by the following formula:

$$V = \sqrt{P \times R}$$

Where

V=Continuous rated DC or AC (rms) working voltage (V)

P=Rated power (W)

R=Resistance value (Ω)

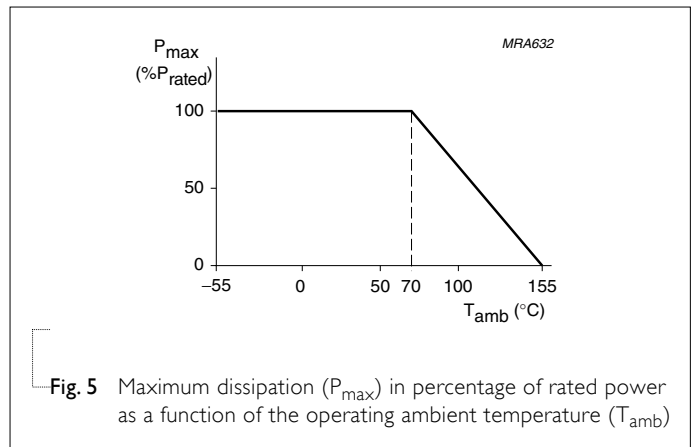


Fig. 5 Maximum dissipation (P<sub>max</sub>) in percentage of rated power as a function of the operating ambient temperature (T<sub>amb</sub>)

TESTS AND REQUIREMENTS

Table 4 Test condition, procedure and requirements

TEST	TEST METHOD	PROCEDURE	REQUIREMENTS	
Temperature Coefficient of Resistance (T.C.R.)	MIL-STD-202F-method 304;	At +25/-55 °C and +25/+125 °C	Refer to table 2	
	JIS C 5202-4.8	<p><b>Formula:</b></p> $T.C.R = \frac{R_2 - R_1}{R_1(t_2 - t_1)} \times 10^6 \text{ (ppm/°C)}$ <p>Where  <math>t_1 = +25 \text{ °C}</math> or specified room temperature  <math>t_2 = -55 \text{ °C}</math> or +125 °C test temperature  <math>R_1 =</math>resistance at reference temperature in ohms  <math>R_2 =</math>resistance at test temperature in ohms</p>		
Thermal Shock	MIL-STD-202F-method 107G; IEC 60115-1 4.19	At -65 (+0/-10) °C for 2 minutes and at +155 (+10/-0) °C for 2 minutes; 25 cycles	±(0.5%+0.05 Ω) for 1% tol. ±(1.0%+0.05 Ω) for 5% tol.	
Low Temperature Operation	MIL-R-55342D-Para 4.7.4	At -65 (+0/-5) °C for 1 hour; RCWV applied for 45 (+5/-0) minutes	±(0.5%+0.05 Ω) for 1% tol. ±(1.0%+0.05 Ω) for 5% tol. No visible damage	
Short Time Overload	MIL-R-55342D-Para 4.7.5; IEC 60115-1 4.13	2.5 × RCWV applied for 5 seconds at room temperature	±(1.0%+0.05 Ω) for 1% tol. ±(2.0%+0.05 Ω) for 5% tol. No visible damage	
Insulation Resistance	MIL-STD-202F-method 302; IEC 60115-1 4.6.1.1	RCOV for 1 minute	≥10 GΩ	
		<table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="text-align: left;"><b>Type</b></td> <td style="text-align: center;"><b>RC2010</b></td> </tr> <tr> <td style="text-align: left;"><b>Voltage (DC)</b></td> <td style="text-align: center;">500 V</td> </tr> </table>		<b>Type</b>
<b>Type</b>	<b>RC2010</b>			
<b>Voltage (DC)</b>	500 V			
Dielectric Withstand Voltage	MIL-STD-202F-method 301; IEC 60115-1 4.6.1.1	Maximum voltage ( $V_{rms}$ ) applied for 1 minute	No breakdown or flashover	
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<b>Type</b>	<b>RC2010</b>			
<b>Voltage (AC)</b>	500 $V_{rms}$			
Resistance to Soldering Heat	MIL-STD-202F-method 210C; IEC 60115-1 4.18	Unmounted chips; 260 ±5 °C for 10 ±1 seconds	±(0.5%+0.05 Ω) for 1% tol. ±(1.0%+0.05 Ω) for 5% tol. No visible damage	
Life	MIL-STD-202F-method 108A; IEC 60115-1 4.25.1	At 70±2 °C for 1,000 hours; RCWV applied for 1.5 hours on and 0.5 hour off	±(1%+0.05 Ω) for 1% tol. ±(3%+0.05 Ω) for 5% tol.	

TEST	TEST METHOD	PROCEDURE	REQUIREMENTS														
<b>Solderability</b>	MIL-STD-202F-method 208A; IEC 60115-1 4.17	Solder bath at 245±3 °C Dipping time: 2±0.5 seconds	Well tinned (≥95% covered) No visible damage														
<b>Bending Strength</b>	JIS C 5202.6.14; IEC 60115-1 4.15	Resistors mounted on a 90 mm glass epoxy resin PCB (FR4) Bending: 2 mm	±(1.0%+0.05 Ω) for 1% tol. ±(1.0%+0.05 Ω) for 5% tol. No visible damage														
<b>Resistance to Solvent</b>	MIL-STD-202F-method 215; IEC 60115-1 4.29	Isopropylalcohol (C <sub>3</sub> H <sub>7</sub> OH) or dichloromethane (CH <sub>2</sub> Cl <sub>2</sub> ) followed by brushing	No smeared														
<b>Noise</b>	JIS C 5202 5.9; IEC 60115-1 4.12	Maximum voltage (V <sub>rms</sub> ) applied.	<table border="1"> <thead> <tr> <th>Resistors range</th> <th>Value</th> </tr> </thead> <tbody> <tr> <td>R &lt; 100 Ω</td> <td>10 dB</td> </tr> <tr> <td>100 Ω ≤ R &lt; 1 KΩ</td> <td>24 dB</td> </tr> <tr> <td>1 KΩ ≤ R &lt; 10 KΩ</td> <td>34 dB</td> </tr> <tr> <td>10 KΩ ≤ R &lt; 100 KΩ</td> <td>44 dB</td> </tr> <tr> <td>100 KΩ ≤ R &lt; 1 MΩ</td> <td>46 dB</td> </tr> <tr> <td>1 MΩ ≤ R ≤ 22 MΩ</td> <td>48 dB</td> </tr> </tbody> </table>	Resistors range	Value	R < 100 Ω	10 dB	100 Ω ≤ R < 1 KΩ	24 dB	1 KΩ ≤ R < 10 KΩ	34 dB	10 KΩ ≤ R < 100 KΩ	44 dB	100 KΩ ≤ R < 1 MΩ	46 dB	1 MΩ ≤ R ≤ 22 MΩ	48 dB
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<b>Humidity (steady state)</b>	JIS C 5202 7.5; IEC 60115-8 4.24.8	1,000 hours; 40±2 °C; 93(+2/-3)% RH RCWV applied for 1.5 hours on and 0.5 hour off	±(0.5%+0.05 Ω) for 1% tol. ±(2.0%+0.05 Ω) for 5% tol.														
<b>Leaching</b>	EIA/IS 4.13B; IEC 60115-8 4.18	Solder bath at 260±5 °C Dipping time: 30±1 seconds	No visible damage														
<b>Intermittent Overload</b>	JIS C 5202 5.8	At room temperature; 2.5 × RCWV applied for 1 second on and 25 seconds off; total 10,000 cycles	±(1.0%+0.05 Ω) for 1% tol. ±(2.0%+0.05 Ω) for 5% tol.														
<b>Resistance to Vibration</b>	On request	On request															
<b>Moisture Resistance Heat</b>	MIL-STD-202F-method 106F; IEC 60115-1 4.24.2	42 cycles; total 1,000 hours Shown as Fig. 6	±(0.5%+0.05Ω) for 1% tol. ±(2.0%+0.05Ω) for 5% tol. No visible damage														

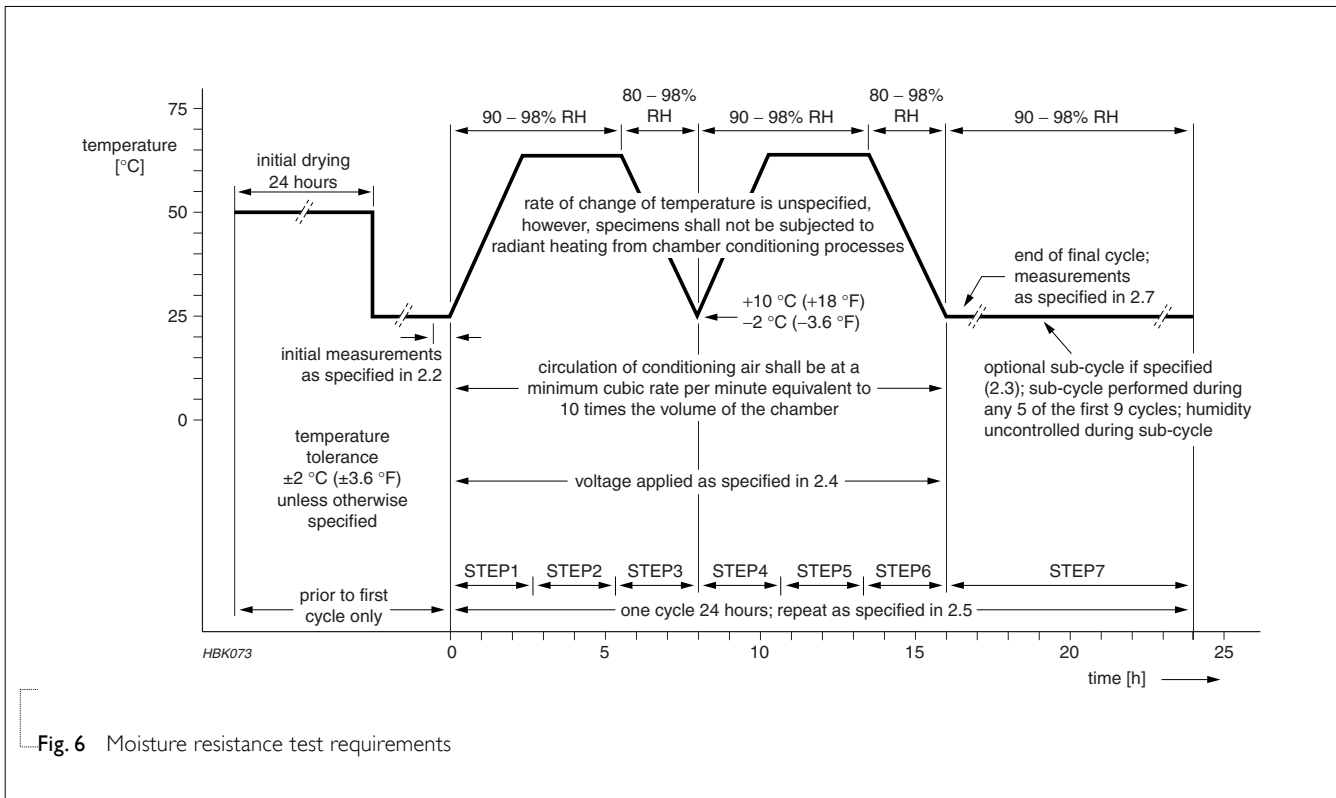


Fig. 6 Moisture resistance test requirements

REVISION HISTORY

REVISION	DATE	CHANGE NOTIFICATION	DESCRIPTION
Version 2	Sep 24, 2004	-	- Test method and procedure updated